

# isc N-Channel MOSFET Transistor

2SK3568

#### • FEATURES

- Drain-source on-resistance:
  R<sub>D</sub>s(on) ≤ 0.52Ω@10V
- Low leakage current: I<sub>DSS</sub> <100 μA @VDS = 500 V
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



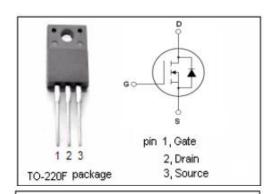
Switching Regulator Applications

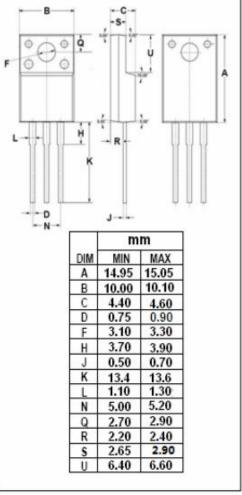
### • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

PARAMETER	VALUE	UNIT	
Drain-Source Voltage	500	V	
Gate-Source Voltage	±30	V	
Drain Current-Continuous	12	А	
Drain Current-Single Pulsed	48	А	
Total Dissipation @T <sub>C</sub> =25℃	40	W	
Max. Operating Junction Temperature	150	$^{\circ}\mathbb{C}$	
Storage Temperature	-55~150	$^{\circ}\mathbb{C}$	
	VDSS    Drain-Source Voltage      Ves    Gate-Source Voltage      ID    Drain Current-Continuous      IDM    Drain Current-Single Pulsed      PD    Total Dissipation @Tc=25°C      Tj    Max. Operating Junction Temperature	Drain-Source Voltage $500$ Gate-Source Voltage $\pm 30$ Drain Current-Continuous $12$ Drain Current-Single Pulsed $48$ Total Dissipation @Tc=25°C $40$ Max. Operating Junction Temperature $150$	

### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	3.125	°C/W	







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### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 10mA	500			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = 10V; I <sub>D</sub> = 1mA	2		4	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =6A			0.52	Ω
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±25V;V <sub>DS</sub> = 0V			±10	μA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =500V; V <sub>GS</sub> = 0V			100	μА
V <sub>SD</sub>	Diode forward voltage	I <sub>S</sub> =12A, V <sub>GS</sub> = 0 V			1.7	V

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